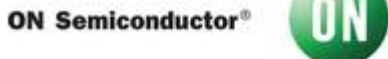




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|----------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------|
|  | <h2 style="color: red;">FCU850N80Z</h2> |
|  <p>Image may be representation. See specs for product details.</p> | Hersteller-Teilenummer: FCU850N80Z |
| | Hersteller / Marke: AMI Semiconductor / ON Semiconductor |
| | Teil der Beschreibung: MOSFET N-CH 800V 6A IPAK |
| | Datenblätter:  FCU850N80Z.pdf |
| | RoHS Status: Bleifrei / RoHS-konform |
| | Lagerzustand: New original, Stock Available. |
| | Liefern von: Hong Kong |
| Versandweg: DHL/Fedex/TNT/UPS/EMS | |









Spezifikationen

| | |
|--------------------------------------------------|---------------------------------------------------------------------|
| Teilenummer | FCU850N80Z |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N-CH 800V 6A IPAK |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | Require For Quote & Check Stock |
| VGS (th) (Max) @ Id | 4.5V @ 600µA |
| Vgs (Max) | ±20V |
| Technologie | MOSFET (Metal Oxide) |
| Supplier Device-Gehäuse | IPAK (TO-251) |
| Serie | SuperFET® II |
| Rds On (Max) @ Id, Vgs | 850 mOhm @ 3A, 10V |
| Verlustleistung (max) | 75W (Tc) |
| Verpackung | Tube |
| Verpackung / Gehäuse | TO-251-3 Short Leads, IPak, TO-251AA |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Through Hole |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |
| Hersteller Standard Vorlaufzeit | 52 Weeks |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Eingabekapazität (Ciss) (Max) @ Vds | 1315pF @ 100V |
| Gate Charge (Qg) (Max) @ Vgs | 29nC @ 10V |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Antriebsspannung (Max Rds On, Min Rds On) | 10V |
| Drain-Source-Spannung (Vdss) | 800V |
| detaillierte Beschreibung | N-Channel 800V 6A (Tc) 75W (Tc) Through Hole IPAK |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 6A (Tc) |

FCU850N80Z Electronic Components ist ein 100% neues Original von YIC Distributor, FCU850N80Z-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, FCU850N80Z AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal.

RFQ FCU850N80Z E-Mail: Info@Y-IC.com

Sie können auch interessiert

| | | | |
|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <p>sein:</p>  <p>FCU7N60TU Fairchild/ON Semiconductor MOSFET N-CH 600V 7A I2PAK</p> |  <p>FCU900N60Z AMI Semiconductor / ON Semiconductor MOSFET N CH 600V 4.5A IPAK</p> |  <p>FCU7N60TU AMI Semiconductor / ON Semiconductor MOSFET N-CH 600V 7A I2PAK</p> |  <p>FCU600N65S3R0 AMI Semiconductor / ON Semiconductor SUPERFET3 650V IPAK PKG</p> |
|  <p>FCU850N80Z Fairchild/ON Semiconductor MOSFET N-CH 800V 6A IPAK</p> |  <p>FCU900N60Z Fairchild/ON Semiconductor MOSFET N CH 600V 4.5A IPAK</p> |  <p>FCU7N60 FAI FCU7N60 FAI</p> |  <p>FCUL0530-R47M=P3 Murata Electronics North America FIXED IND 470NH 16A 2.85 MOHM</p> |

Verwandtes Hot-Keyword

Mehr

| | | | | |
|-----------------------------------------------------------------|----------------------------------------|-----------------------------------------|----------------------------------|-----------------------------------------------------------------|
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| FCU850N80Z Electronic | FCU850N80Z-Komponenten | FCU850N80Z-Verteiler | FCU850N80Z-Bild | FCU850N80Z-Teil |
| FCU850N80Z Preis | FCU850N80Z Hersteller | FCU850N80Z Bild | FCU850N80Z Aktie | FCU850N80Z Inventar |
| FCU850N80Z Neu | FCU850N80Z Original | FCU850N80Z garantiert | FCU850N80Z RFQ | FCU850N80Z Online bestellen |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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